

# PS2801C-1, PS2801C-4

HIGH ISOLATION VOLTAGE SSOP PHOTOCOUPLER

## DESCRIPTION

These products are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor in a plastic SSOP for high density applications to realize an excellent cost performance.

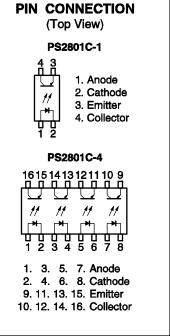
This package has shield effect to cut off ambient light.

#### **FEATURES**

- High isolation voltage (BV = 2 500 Vr.m.s.)
- Small and thin package (4, 16-pin SSOP, Pin pitch 1.27 mm)
- High collector to emitter voltage (V<sub>CEO</sub> : 80 V)
- Ordering number of tape product: PS2801C-1-F3, PS2801C-4-F3
- Pb-Free product
- Safety standards
  - UL approved: UL1577, Single protection
  - CSA approved: CAN/CSA-C22.2 No. 62368-1, Basic insulation
  - BSI approved: BS EN 62368-1, Basic/Supplementary insulation (PS2801C-1 only)
  - VDE approved: DIN EN 60747-5-5 (Option)

#### APPLICATIONS

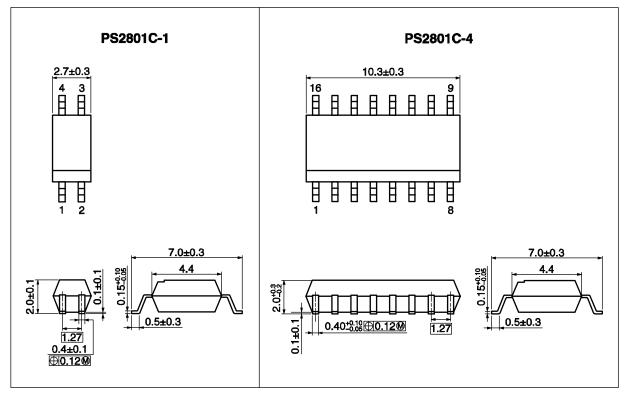
- Programmable logic controllers
- Measuring instruments
- Power supply
- Hybrid IC



R08DS0072EJ0402 Rev.4.02 Oct 11, 2019



## PACKAGE DIMENSIONS (UNIT: mm)



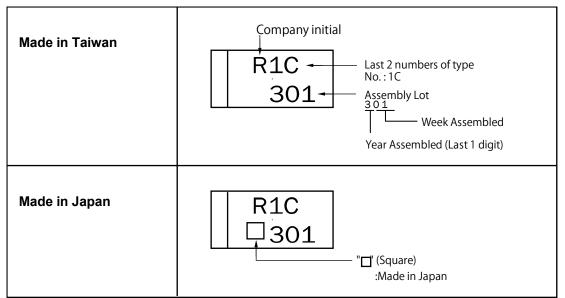
## PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	4.5 mm
Creepage Distance	4.5 mm
Isolation Distance	0.1 mm

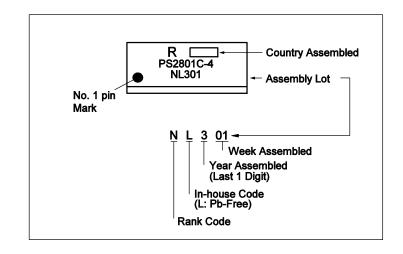


## MARKING EXAMPLE

#### PS2801C-1



#### PS2801C-4





#### **ORDERING INFORMATION**

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number <sup>*1</sup>
PS2801C-1	PS2801C-1-A	Pb-Free	50 pcs (Tape 50 pcs cut)	Standard products	PS2801C-1
PS2801C-1-F3	PS2801C-1-F3-A		Embossed Tape 3 500 pcs/reel	(UL, CSA, BSI approved)	
PS2801C-4	PS2801C-4-A		10 pcs (Tape 10 pcs cut)	Standard products	PS2801C-4
PS2801C-4-F3	PS2801C-4-F3-A		Embossed Tape 2 500 pcs/reel	(UL, CSA approved)	
PS2801C-1-V	PS2801C-1-V-A		50 pcs (Tape 50 pcs cut)	UL, CSA, BSI,	PS2801C-1
PS2801C-1-V-F3	PS2801C-1-V-F3-A		Embossed Tape 3 500 pcs/reel	DIN EN 60747-5-5 approved	
PS2801C-4-V	PS2801C-4-V-A		10 pcs (Tape 10 pcs cut)	UL, CSA,	PS2801C-4
PS2801C-4-V-F3	PS2801C-4-V-F3-A		Embossed Tape 2 500 pcs/reel	DIN EN 60747-5-5 approved	

Note: \*1. For the application of the Safety Standard, following part number should be used.

#### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C, unless otherwise specified)

Parameter		Symbol	Rat	ings	Unit
			PS2801C-1	PS2801C-4	
Diode	Forward Current (DC)	I <sub>F</sub>	3	80	mA/ch
	Reverse Voltage	V <sub>R</sub>		6	V
	Power Dissipation Derating	⊿P <sub>D</sub> /°C	0.6	0.8	mW/°C
	Power Dissipation	PD	60	80	mW/ch
	Peak Forward Current *1	I <sub>FP</sub>	0.5		A/ch
Transistor	Collector to Emitter Voltage	V <sub>CEO</sub>	80		V
	Emitter to Collector Voltage	V <sub>ECO</sub>		5	V
	Collector Current	lc	3	80	mA/ch
	Power Dissipation Derating	⊿P <sub>c</sub> /°C	1.2		mW/°C
	Power Dissipation	Pc	120		mW/ch
Isolation Vo	bltage *2	BV	2 5	500	Vr.m.s.
Operating Ambient Temperature		T <sub>A</sub>	–55 to +100		°C
Storage Temperature		T <sub>stg</sub>	–55 to +150		°C

Notes: \*1. PW = 100 μs, Duty Cycle = 1%

\*2. AC voltage for 1 minute at  $T_A = 25^{\circ}$ C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together (PS2801C-1). Pins 1-8 shorted together, 9-16 shorted together (PS2801C-4).



## ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ )

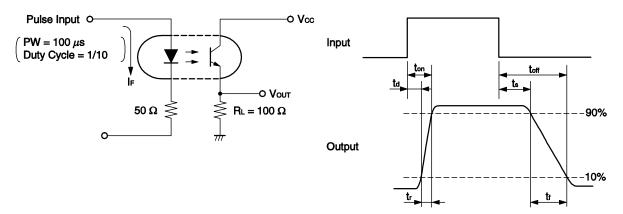
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 5 mA		1.2	1.4	V
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 5 V			5	μA
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		10		pF
Transistor	Collector to Emitter Dark Current	I <sub>CEO</sub>	$V_{CE} = 80 \text{ V}, \text{ I}_{F} = 0 \text{ mA}$			100	nA
Coupled	Current Transfer Ratio $(I_C/I_F)^{*1}$	CTR	I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V	50		400	%
	Collector Saturation Voltage	V <sub>CE (sat)</sub>	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 2 mA		0.13	0.3	V
	Isolation Resistance	R <sub>I-0</sub>	V <sub>I-O</sub> = 1.0 kV <sub>DC</sub>	10 <sup>11</sup>			Ω
	Isolation Capacitance	CI-O	V = 0 V, f = 1.0 MHz		0.4		pF
	Rise Time *2	tr	$V_{CC}$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$		5		μs
	Fall Time *2	t <sub>f</sub>			7		
	Turn-on Time *2	t <sub>on</sub>	]		10		
	Turn-off Time *2	t <sub>off</sub>	]		7		

#### Notes: \*1. CTR rank

PS2801C-1

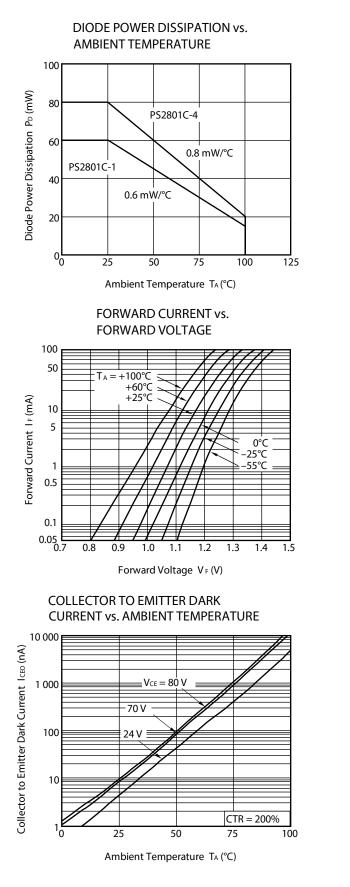
N : 50 to 400 (%) P : 150 to 300 (%) L : 100 to 300 (%) M : 100 to 400 (%) PS2801C-4 N : 50 to 400 (%) M : 100 to 400 (%)

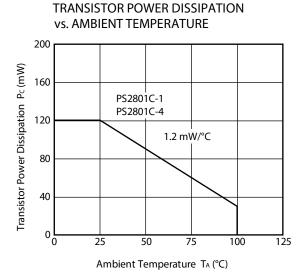
\*2. Test circuit for switching time



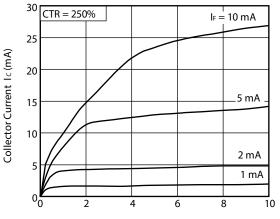


## **TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, unless otherwise specified)**



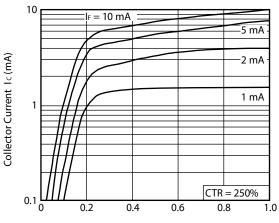


COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



Collector to Emitter Voltage VCE (V)

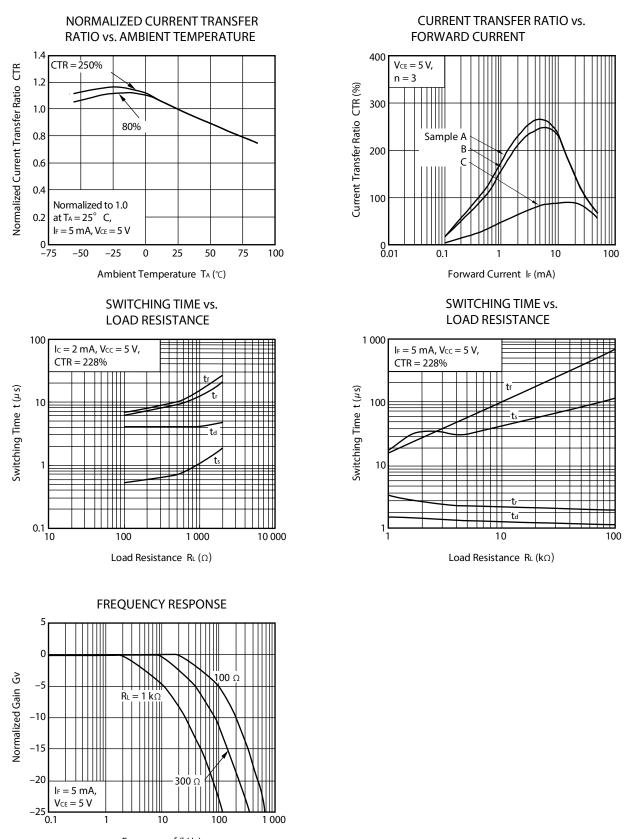
COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE



Collector Saturation Voltage V<sub>CE (sat)</sub> (V)

**Remark** The graphs indicate nominal characteristics.



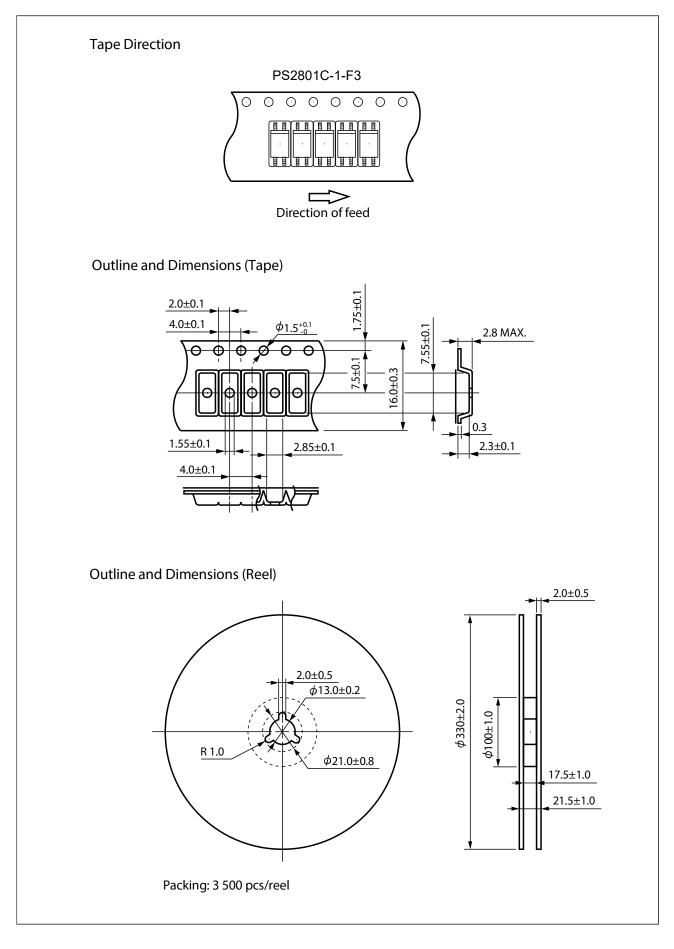


Frequency f (kHz)

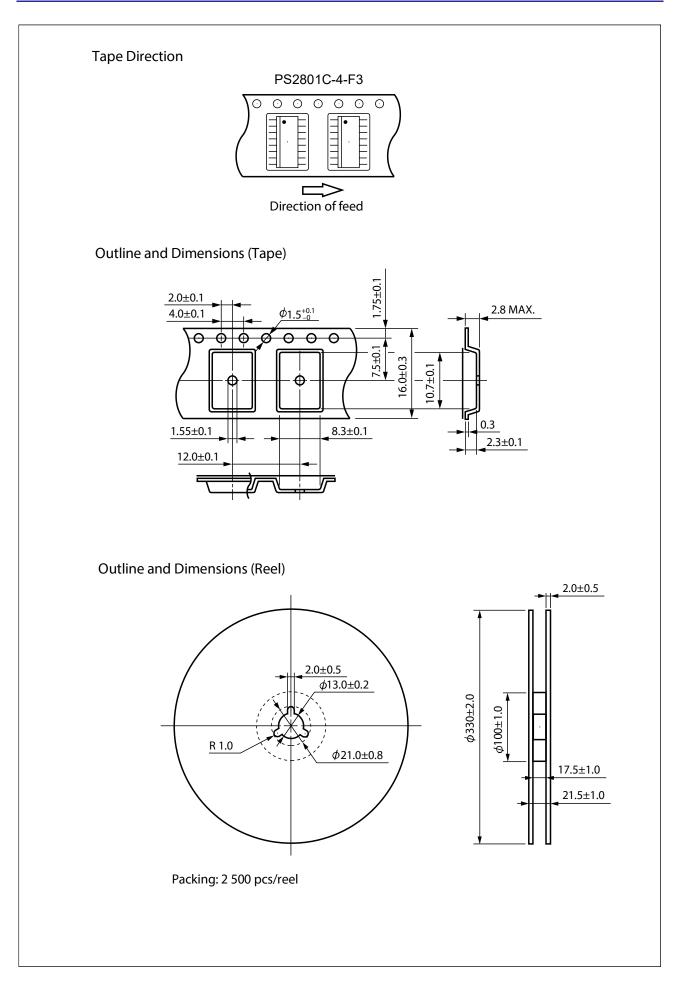
**Remark** The graphs indicate nominal characteristics.



## TAPING SPECIFICATIONS (UNIT: mm)

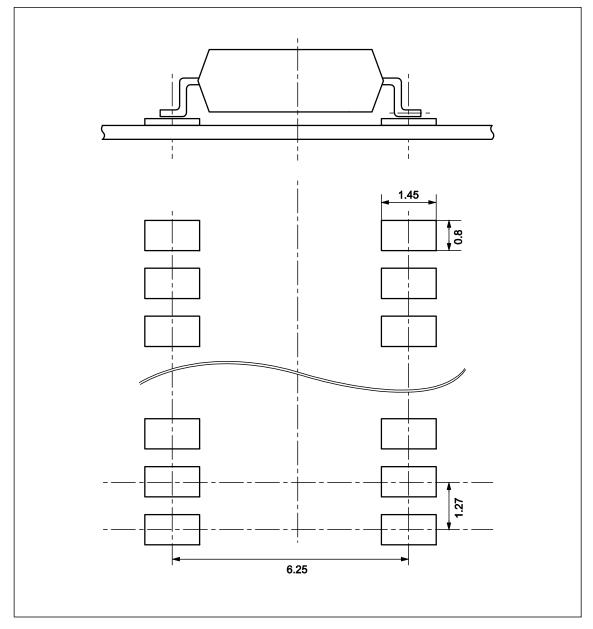








## **RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)**



**Remark** All dimensions in this figure must be evaluated before use.



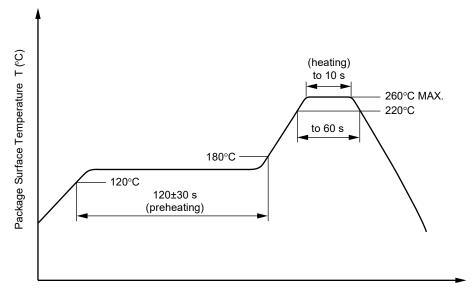
#### NOTES ON HANDLING

- 1. Recommended soldering conditions
  - (1) Infrared reflow soldering
    - · Peak reflow temperature
    - Time of peak reflow temperature
    - Time of temperature higher than 220°C
    - Time to preheat temperature from 120 to 180°C
    - Number of reflows
    - Flux

#### 10 seconds or less 60 seconds or less 120±30 s Three Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

260°C or below (package surface temperature)

#### Recommended Temperature Profile of Infrared Reflow



Time (s)

#### (2) Wave soldering

#### Temperature

- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)

260°C or below (molten solder temperature)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

#### (3) Soldering by Soldering Iron

- Peak Temperature (lead part temperature) 350°C or below
  - 3 seconds or less

Time (each pins)Flux

- o secondo or 1855
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)
- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100°C
- (4) Cautions
  - Flux Cleaning

Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents. •Do not use fixing agents or coatings containing halogen-based substances.



#### 2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

 Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. This tendency may sometimes be obvious, especially below  $I_F = 1$  mA.

Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

## **USAGE CAUTIONS**

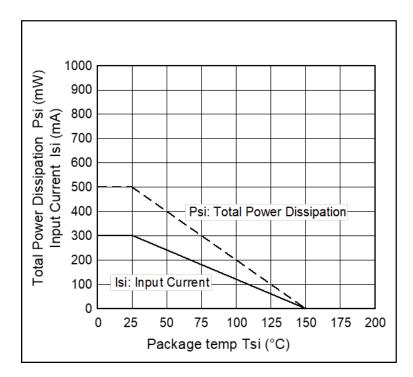
- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.



SPECIFICATION OF	VDE	MARKS	LICENSE	DOCUMENT
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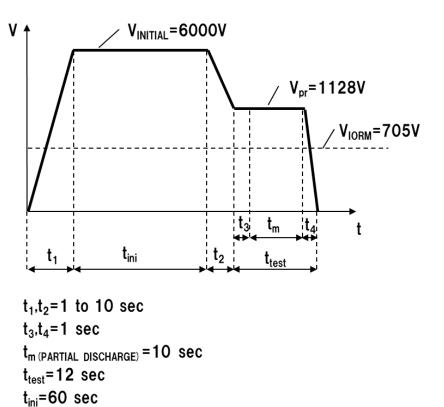
Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength			
maximum operating isolation voltage	UIORM	705	$V_{peak}$
Test voltage (partial discharge test, procedure a for type test and	Upr	1 128	V <sub>peak</sub>
random test)			
$U_{pr}$ = 1.6 × $U_{IORM}$ , $P_d$ < 5 pC			
Test voltage (partial discharge test, procedure b for all devices)	Upr	1 322	V <sub>peak</sub>
$U_{pr}$ = 1.875 × $U_{IORM}$ , $P_d < 5 \ pC$			
Highest permissible overvoltage	UIOTM	6 000	V <sub>peak</sub>
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	СТІ	175	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		III a	
Storage temperature range	T <sub>stg</sub>	-55 to +150	°C
Operating temperature range	TA	-55 to +100	°C
Isolation resistance, minimum value			
$V_{IO} = 500 \text{ V dc at } T_A = 25^{\circ}\text{C}$	Ris MIN.	10 <sup>12</sup>	Ω
V <sub>IO</sub> = 500 V dc at T <sub>A</sub> MAX. at least 100°C	Ris MIN.	1011	Ω
Safety maximum ratings (maximum permissible in case of fault, see			
thermal derating curve)			
Package temperature	Tsi	150	°C
Current (input current I <sub>F</sub> , Psi = 0)	lsi	300	mA
Power (output or total power dissipation)	Psi	500	mW
Isolation resistance			
V <sub>IO</sub> = 500 V dc at T <sub>A</sub> = Tsi	Ris MIN.	10 <sup>9</sup>	Ω

## Dependence of maximum safety ratings with package temperature

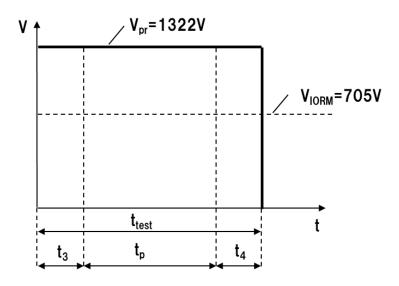








#### Method b) Non-destructive Test, 100% Production Test



 $t_3, t_4 = 0.1$  sec  $t_{p (PARTIAL DISCHARGE)} = 1.0$  sec  $t_{test} = 1.2$  sec

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	<ol> <li>Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.</li> </ol>
	2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	• Do not lick the product or i any way allow it to enter the mouth.

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#### Notice



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